



ELECTRONICS, INC.

44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089

<http://www.nteinc.com>

NTE2056 Integrated Circuit 8-Bit Multiplying Digital-to-Analog Converter

Description:

The NTE2056 is an 8-bit multiplying D-to-A converter in a 16-Lead DIP type package designed for use where the output current is a linear product of an eight-bit digital word and an analog input voltage.

Features:

- Fast Setting Time: 300ns Typ
- Non-Inverting Digital Inputs are MTTL and CMOS Compatible
- Output Voltage Swing: +0.4V to -5.0V
- High-Speed Multipling Input: Slew Rate 4.0mA/μs
- Standard Supply Voltages: +5.0V and -5.0V to -15V

Applications:

- | | |
|---|--|
| <ul style="list-style-type: none"> ● Tracking A-to-D Converters ● Successive Approximation A-to-D Converters ● 2 1/2 Digit Panel Meters and DVM's ● Waveform Synthesis ● Sample and Hold ● Peak Detector ● Programmable Gain and Attenuation ● CRT Character Generation | <ul style="list-style-type: none"> ● Audio Digitizing and Decoding ● Programmable Power Supplies ● Analog-Digital Multiplication ● Digital-Digital Multiplication ● Analog-Digital Division ● Digital Addition and Subtraction ● Speech Compression and Expansion ● Stepping Motor Drive |
|---|--|

Absolute Maximum Ratings: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Power Supply Voltage

V_{CC}	+5.5V
V_{EE}	-16.5V

Digital Input Voltage, V_5 thru V_{12} 0 to +5.5V

Applied Output Voltage, V_O +0.5V, -5.2V

Reference Current, I_{14} 5mA

Reference Amplifier Inputs

V_{14}	V_{CC}
V_{15}	V_{EE}

Operating Temperature Range, T_A 0° to $+75^\circ\text{C}$

Storage Temperature Range, T_{stg} -65° to $+150^\circ\text{C}$

Electrical Characteristics: ($T_A = 0^\circ$ to $+75^\circ\text{C}$, $V_{CC} = +5\text{V}$, $V_{EE} = -15\text{V}$, $V_{ref}/R14 = 2\text{mA}$, All digital inputs at high logic level, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Relative Accuracy (Error relative to full scale I_O)	E_r	Note 1	-	-	± 0.78	%
Setting Time to within $\pm 1/2$ LSB (Includes t_{PLH})	t_S	$T_A = +25^\circ\text{C}$, Note 2	-	300	-	ns
Propagation Delay Time	t_{PLH} , t_{PHL}	$T_A = +25^\circ\text{C}$	-	30	100	ns
Output Full Scale Current Drift	TCI_O		-	-20	-	PPM/ $^\circ\text{C}$
Digital Input Logic Levels (MSB) High Level, Logic "1"	V_{IH}		2.0	-	-	V
Low Level, Logic "0"	V_{IL}		-	-	0.8	V
Digital Input Current (MSB) High Level	I_{IH}	$V_{IH} = 5\text{V}$	-	0	0.04	mA
Low Level	I_{IL}	$V_{IL} = 0.8\text{V}$	-	-0.4	-0.8	mA
Reference Input Bias Current (Pin15)	I_{15}		-	-1.0	-5.0	μA
Output Current Range	I_{OR}	$V_{EE} = -5\text{V}$	0	2.0	2.1	mA
		$V_{EE} = -15\text{V}$, $T_A = +25^\circ\text{C}$	0	2.0	4.2	mA
Output Current	I_O	$V_{ref} = 2.000\text{V}$, $R14 = 1000\Omega$	1.9	1.99	2.1	mA
	$I_{O(\text{min})}$	All bits low	-	0	4.0	μA
Output Voltage Compliance	V_O	$E_r \leq 0.19\%$, $T_A = +25^\circ\text{C}$ Pin1 Grounded	-	-	-0.55, +0.4	V
		Pin1 Open, V_{EE} below -10V	-	-	-5.0, +0.4	V
Reference Current Slew Rate	SR I_{ref}		-	4.0	-	mA/ μs
Output Current Power Supply Sensitivity	PSRR(-)		-	0.5	2.7	$\mu\text{A}/\text{V}$
Power Supply Current	I_{CC}	All bits low	-	+13.5	+22.0	mA
	I_{EE}		-	-7.5	-13.0	mA
Power Supply Voltage Range	V_{CCR}	$T_A = +25^\circ\text{C}$	+4.5	+5.0	+5.5	V
	V_{EER}		-4.5	-15.0	-16.5	V
Power Dissipation All bits low	P_D	$V_{EE} = -5\text{V}$	-	105	170	mW
		$V_{EE} = -15\text{V}$	-	190	305	mW
		$V_{EE} = -5\text{V}$	-	90	-	mW
		$V_{EE} = -15\text{V}$	-	160	-	mW
All bits high						

Note 1. All current switches are tested to guarantee at least 50% of rated output current.

Note 2. All bits switched.

Pin Connection Diagram

